

# 74ABT541

## Octal Buffer/Line Driver with 3-STATE Outputs

### Features

- Non-inverting buffers
- Output sink capability of 64mA, source capability of 32mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50pF and 250pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High-impedance, glitch-free bus loading during entire power up and power down cycle
- Nondestructive, hot-insertion capability
- Flow-through pinout for ease of PC board layout
- Disable time less than enable time to avoid bus contention

### General Description

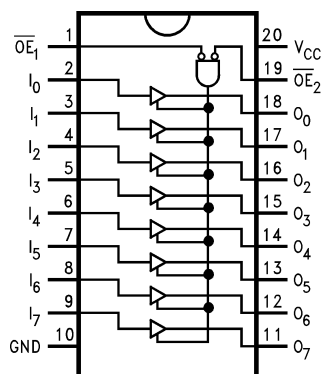
The ABT541 is an octal buffer and line driver with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The ABT541 is similar to the ABT244 with broadside pinout.

### Ordering Information

Order Number	Package Number	Package Description
74ABT541CSC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74ABT541CSJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74ABT541CMSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide
74ABT541CMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix "X" to the ordering number.  
Pb-Free package per JEDEC J-STD-020B.

### Connection Diagram



### Pin Descriptions

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	Output Enable Input (Active LOW)
$I_0-I_7$	Inputs
$O_0-O_7$	Outputs

## Truth Table

Inputs			Outputs
$\overline{OE}_1$	$\overline{OE}_2$	I	
L	L	H	H
H	X	X	Z
X	H	X	Z
L	L	L	L

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
$T_{STG}$	Storage Temperature	$-65^{\circ}\text{C}$ to $+150^{\circ}\text{C}$
$T_A$	Ambient Temperature Under Bias	$-55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$
$T_J$	Junction Temperature Under Bias	$-55^{\circ}\text{C}$ to $+150^{\circ}\text{C}$
$V_{CC}$	$V_{CC}$ Pin Potential to Ground Pin	$-0.5\text{V}$ to $+7.0\text{V}$
$V_{IN}$	Input Voltage <sup>(1)</sup>	$-0.5\text{V}$ to $+7.0\text{V}$
$I_{IN}$	Input Current <sup>(1)</sup>	$-30\text{mA}$ to $+5.0\text{mA}$
$V_O$	Voltage Applied to Any Output Disabled or Power-Off State HIGH State	$-0.5\text{V}$ to $5.5\text{V}$ $-0.5\text{V}$ to $V_{CC}$
	Current Applied to Output in LOW State (Max.)	twice the rated $I_{OL}$ (mA)
	DC Latchup Source Current	$-500\text{mA}$
	Over Voltage Latchup (I/O)	10V

### Note:

1. Either voltage limit or current limit is sufficient to protect inputs.

## Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
$T_A$	Free Air Ambient Temperature	$-40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$
$V_{CC}$	Supply Voltage	$+4.5\text{V}$ to $+5.5\text{V}$
$\Delta V / \Delta t$	Minimum Input Edge Rate Data Input Enable Input	50mV/ns 20mV/ns

## DC Electrical Characteristics

Symbol	Parameter		$V_{CC}$	Conditions	Min.	Typ.	Max.	Units
$V_{IH}$	Input HIGH Voltage			Recognized HIGH Signal	2.0			V
$V_{IL}$	Input LOW Voltage			Recognized LOW Signal			0.8	V
$V_{CD}$	Input Clamp Diode Voltage		Min.	$I_{IN} = -18\text{mA}$			-1.2	V
$V_{OH}$	Output HIGH Voltage		Min.	$I_{OH} = -3\text{mA}$	2.5			V
				$I_{OH} = -32\text{mA}$	2.0			V
$V_{OL}$	Output LOW Voltage		Min.	$I_{OL} = 64\text{mA}$			0.55	V
$I_{IH}$	Input HIGH Current		Max.	$V_{IN} = 2.7\text{V}^{(3)}$			1	$\mu\text{A}$
				$V_{IN} = V_{CC}$			1	
$I_{BVI}$	Input HIGH Current Breakdown Test		Max.	$V_{IN} = 7.0\text{V}$			7	$\mu\text{A}$
$I_{IL}$	Input LOW Current		Max.	$V_{IN} = 0.5\text{V}^{(3)}$			-1	$\mu\text{A}$
				$V_{IN} = 0.0\text{V}$			-1	
$V_{ID}$	Input Leakage Test		0.0	$I_{ID} = 1.9\mu\text{A}$ , All Other Pins Grounded	4.75			V
$I_{OZH}$	Output Leakage Current		0–5.5V	$V_{OUT} = 2.7\text{V}$ , $\overline{OE}_n = 2.0\text{V}$			10	$\mu\text{A}$
$I_{OZL}$	Output Leakage Current		0–5.5V	$V_{OUT} = 0.5\text{V}$ , $\overline{OE}_n = 2.0\text{V}$			-10	$\mu\text{A}$
$I_{OS}$	Output Short-Circuit Current		Max.	$V_{OUT} = 0.0\text{V}$	-100		-275	mA
$I_{CEX}$	Output HIGH Leakage Current		Max.	$V_{OUT} = V_{CC}$			50	$\mu\text{A}$
$I_{ZZ}$	Bus Drainage Test		0.0	$V_{OUT} = 5.5\text{V}$ , All Others GND			100	$\mu\text{A}$
$I_{CCH}$	Power Supply Current		Max.	All Outputs HIGH			50	$\mu\text{A}$
$I_{CCL}$	Power Supply Current		Max.	All Outputs LOW			30	mA
$I_{CCZ}$	Power Supply Current		Max.	$\overline{OE}_n = V_{CC}$ , All Others at $V_{CC}$ or Ground			50	$\mu\text{A}$
$I_{CCT}$	Additional $I_{CC}$ /Input	Outputs Enabled		$V_I = V_{CC} - 2.1\text{V}$			2.5	mA
		Outputs 3-STATE	Max.	Enable Input $V_I = V_{CC} - 2.1\text{V}$			2.5	mA
		Outputs 3-STATE		Data Input $V_I = V_{CC} - 2.1\text{V}$ , All Others at $V_{CC}$ or Ground			50	$\mu\text{A}$
$I_{CCD}$	Dynamic $I_{CC}$ No Load <sup>(3)</sup>		Max	Outputs Open, $\overline{OE}_n = \text{GND}$ , One-Bit Toggling <sup>(2)</sup> , 50% Duty Cycle			0.1	mA/MHz

## Notes:

2. For 8-bit toggling,  $I_{CCD} < 0.8\text{mA/MHz}$ .

3. Guaranteed, but not tested.

## DC Electrical Characteristics

SOIC package.

Symbol	Parameter	$V_{CC}$	Conditions $C_L = 50\text{pF}$ , $R_L = 500\Omega$	Min.	Typ.	Max.	Units
$V_{OLP}$	Quiet Output Maximum Dynamic $V_{OL}$	5.0	$T_A = 25^\circ\text{C}^{(4)}$		0.7	1.0	V
$V_{OLV}$	Quiet Output Minimum Dynamic $V_{OL}$	5.0	$T_A = 25^\circ\text{C}^{(4)}$	-1.3	-0.8		V
$V_{OHV}$	Minimum HIGH Level Dynamic Output Voltage	5.0	$T_A = 25^\circ\text{C}^{(5)}$	2.7	3.1		V
$V_{IHD}$	Minimum HIGH Level Dynamic Input Voltage	5.0	$T_A = 25^\circ\text{C}^{(6)}$	2.0	1.4		V
$V_{ILD}$	Maximum LOW Level Dynamic Input Voltage	5.0	$T_A = 25^\circ\text{C}^{(6)}$		1.1	0.6	V

### Notes:

- Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.
- Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.
- Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold ( $V_{ILD}$ ), 0V to threshold ( $V_{IHD}$ ). Guaranteed, but not tested.

## AC Electrical Characteristics

SOIC and SSOP package.

Symbol	Parameter	$T_A = +25^\circ\text{C}$ , $V_{CC} = +5\text{V}$ , $C_L = 50\text{pF}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$ , $V_{CC} = 4.5\text{V}–5.5\text{V}$ , $C_L = 50\text{pF}$		Units
		Min.	Typ.	Max.	Min.	Max.	
$t_{PLH}$	Propagation Delay, Data to Outputs	1.0	2.0	3.6	1.0	3.6	ns
$t_{PHL}$		1.0	2.4	3.6	1.0	3.6	
$t_{PZH}$	Output Enable Time	1.5	3.1	6.0	1.5	6.0	ns
$t_{PZL}$		1.5	3.7	6.0	1.5	6.0	
$t_{PHZ}$	Output Disable Time	1.7	3.5	6.1	1.7	6.1	ns
$t_{PLZ}$		1.7	3.1	5.6	1.7	5.6	

**Extended AC Electrical Characteristics**

SOIC package.

Symbol	Parameter	–40°C to +85°C, V <sub>CC</sub> = 4.5V to 5.5V, C <sub>L</sub> = 50pF, 8 Outputs Switching <sup>(7)</sup>			T <sub>A</sub> = –40°C to +85°C, V <sub>CC</sub> = 4.5V to 5.5V, C <sub>L</sub> = 250pF, 1 Output Switching <sup>(8)</sup>		T <sub>A</sub> = –40°C to +85°C, V <sub>CC</sub> = 4.5V to 5.5V, C <sub>L</sub> = 250pF, 8 Outputs Switching <sup>(9)</sup>		Units
		Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
f <sub>TOGGLE</sub>	Max Toggle Frequency		100						MHz
t <sub>PLH</sub>	Propagation Delay, Data to Outputs	1.5		5.0	1.5	6.0	2.5	8.5	ns
t <sub>PHL</sub>		1.5		5.0	1.5	6.0	2.5	8.5	
t <sub>PZH</sub>	Output Enable Time	1.5		6.5	2.5	7.5	2.5	9.5	ns
t <sub>PZL</sub>		1.5		6.5	2.5	7.5	2.5	10.5	
t <sub>PHZ</sub>	Output Disable Time	1.0		6.1	(10)				ns
t <sub>PLZ</sub>		1.0		5.6					

**Notes:**

7. This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).
8. This specification is guaranteed but not tested. The limits represent propagation delay with 250pF load capacitors in place of the 50pF load capacitors in the standard AC load. This specification pertains to single output switching only.
9. This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250pF load capacitors in place of the 50pF load capacitors in the standard AC load.
10. The 3-STATE delays are dominated by the RC network (500Ω, 250pF) on the output and have been excluded from the datasheet.

## Skew

SOIC package.

Symbol	Parameter	$T_A = -40^\circ\text{C to } +85^\circ\text{C},$ $V_{CC} = 4.5\text{V to } 5.5\text{V},$ $C_L = 50\text{pF},$ 8 Outputs Switching <sup>(11)</sup>	$T_A = -40^\circ\text{C to } +85^\circ\text{C},$ $V_{CC} = 4.5\text{V to } 5.5\text{V},$ $C_L = 250\text{pF},$ 8 Outputs Switching <sup>(12)</sup>	Units
		Max.	Max.	
$t_{OSHL}^{(13)}$	Pin to Pin Skew, HL Transitions	1.3	2.3	ns
$t_{OSLH}^{(13)}$	Pin to Pin Skew, LH Transitions	1.0	1.8	ns
$t_{PS}^{(14)}$	Duty Cycle, LH/HL Skew	2.0	3.5	ns
$t_{OST}^{(13)}$	Pin to Pin Skew, LH/HL Transitions	2.0	3.5	ns
$t_{PV}^{(15)}$	Device to Device Skew, LH/HL Transitions	2.0	3.5	ns

### Notes:

11. This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)
12. These specifications guaranteed but not tested. The limits represent propagation delays with 250pF load capacitors in place of the 50pF load capacitors in the standard AC load.
13. Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH-to-LOW ( $t_{OSHL}$ ), LOW-to-HIGH ( $t_{OSLH}$ ), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW ( $t_{OST}$ ). The specification is guaranteed but not tested.
14. This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.
15. Propagation delay variation for a given set of conditions (i.e., temperature and  $V_{CC}$ ) from device to device. This specification is guaranteed but not tested.

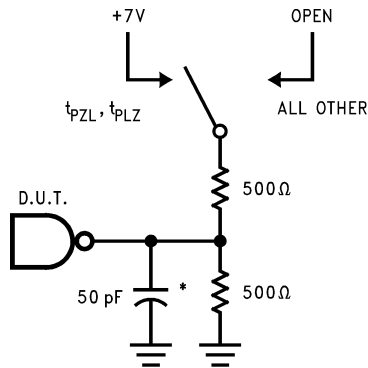
## Capacitance

Symbol	Parameter	Conditions $T_A = 25^\circ\text{C}$	Typ.	Units
$C_{IN}$	Input Capacitance	$V_{CC} = 0.0\text{V}$	5.0	pF
$C_{OUT}^{(16)}$	Output Capacitance	$V_{CC} = 5.0\text{V}$	9.0	pF

### Note:

16.  $C_{OUT}$  is measured at frequency of  $f = 1\text{ MHz}$ , per MIL-STD-883, Method 3012.

## AC Loading



\*Includes jig and probe capacitance

Figure 1. Standard AC Test Load

Amplitude	Rep. Rate	$t_w$	$t_r$	$t_f$
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

Figure 3. Test Input Signal Requirements

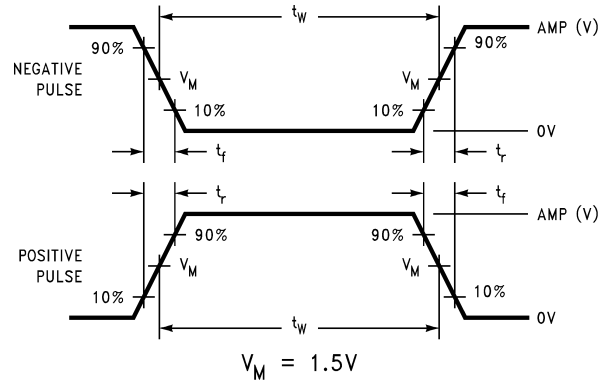


Figure 2. Test Input Signal Levels

## AC Waveforms

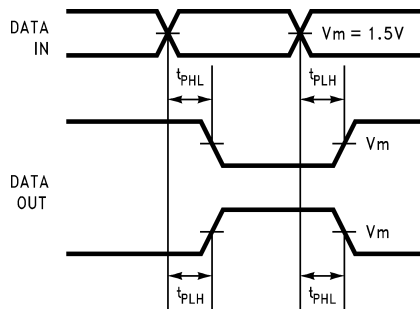


Figure 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

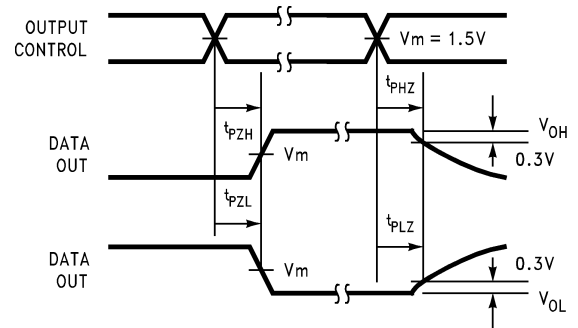


Figure 6. 3-STATE Output HIGH and LOW Enable and Disable Time

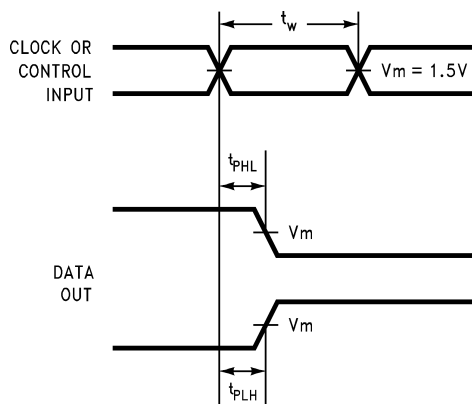


Figure 5. Propagation Delay, Pulse Width Waveforms

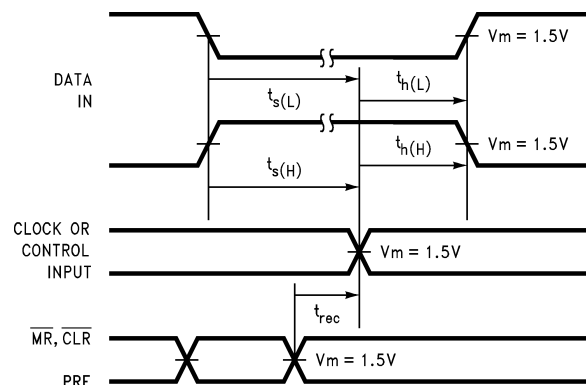
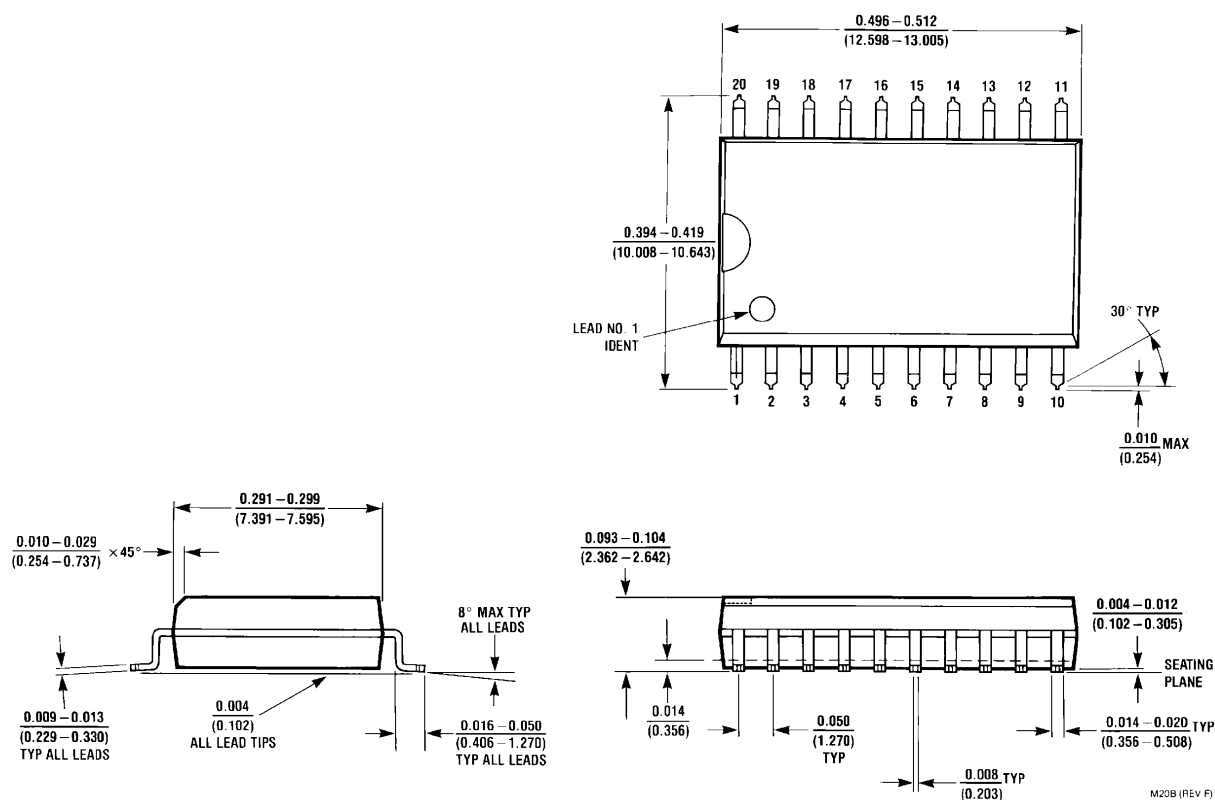


Figure 7. Setup Time, Hold Time and Recovery Time Waveforms

## Physical Dimensions

Dimensions are in inches (millimeters) unless otherwise noted.

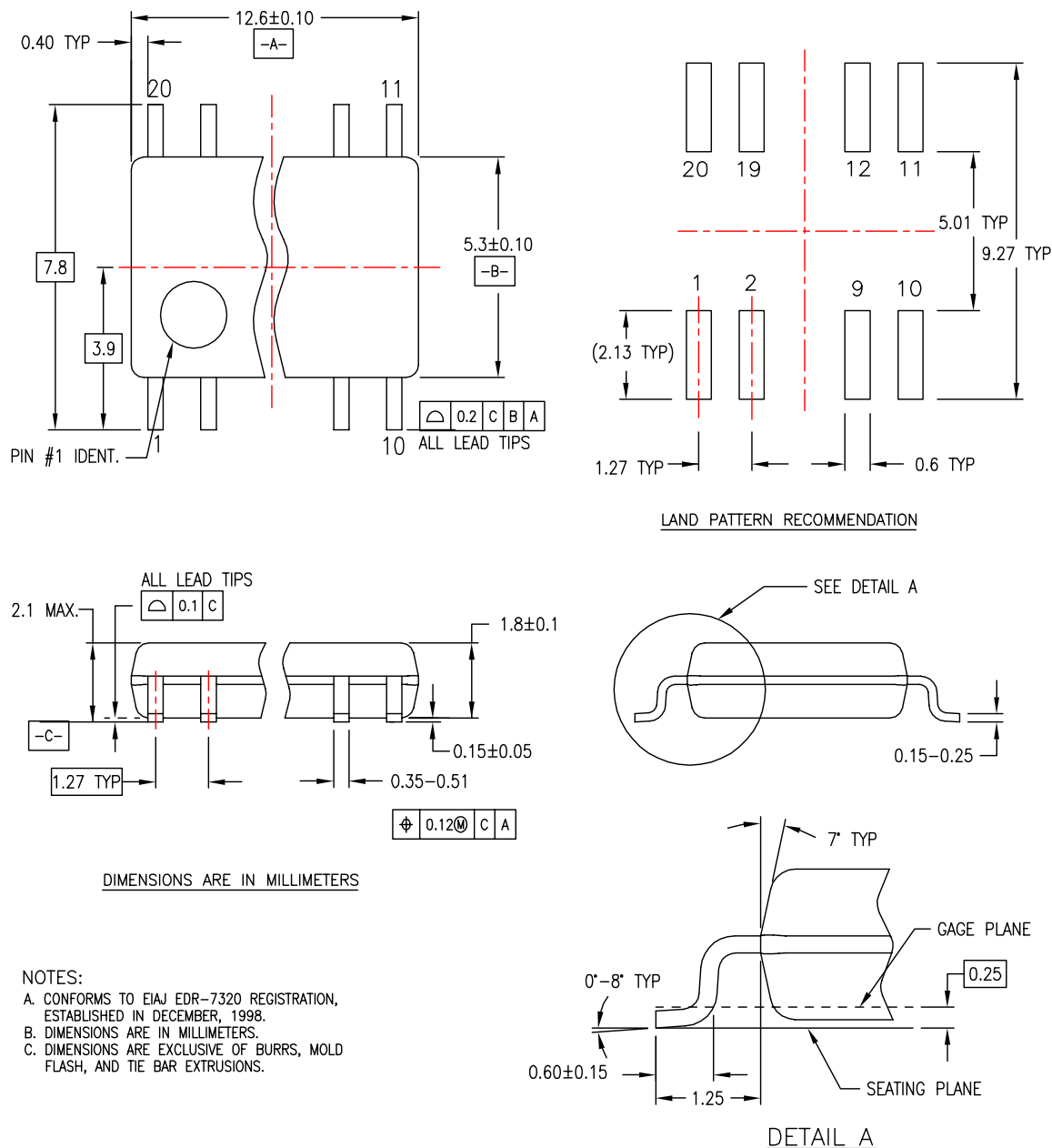


**Figure 8. 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide  
Package Number M20B**



**Physical Dimensions (Continued)**

Dimensions are in millimeters unless otherwise noted.

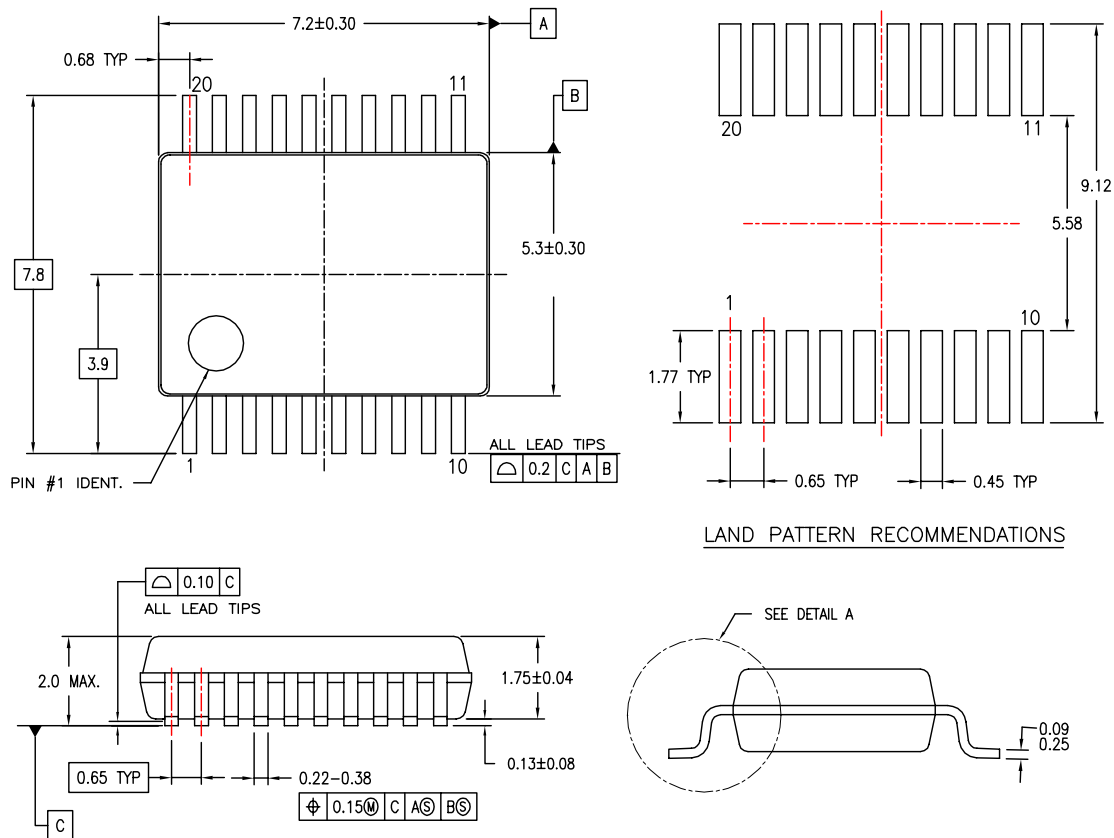


M20DREVC

**Figure 9. 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide**  
**Package Number M20D**

**Physical Dimensions** (Continued)

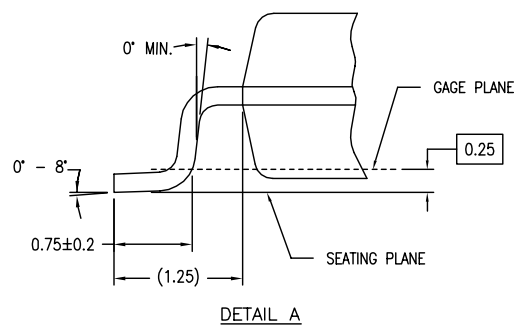
Dimensions are in millimeters unless otherwise noted.



DIMENSIONS ARE IN MILLIMETERS

## NOTES:

- CONFORMS TO JEDEC REGISTRATION MO-150, VARIATION AE, DATE 1/94.
- DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- DIMENSIONS AND TOLERANCES PER ASME Y14.5M - 1994.

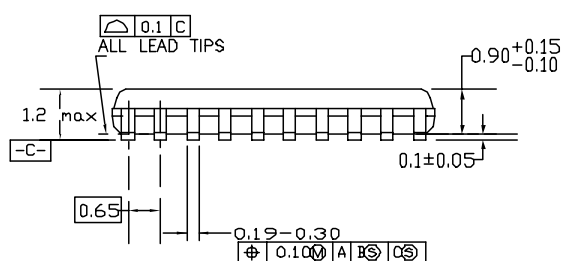
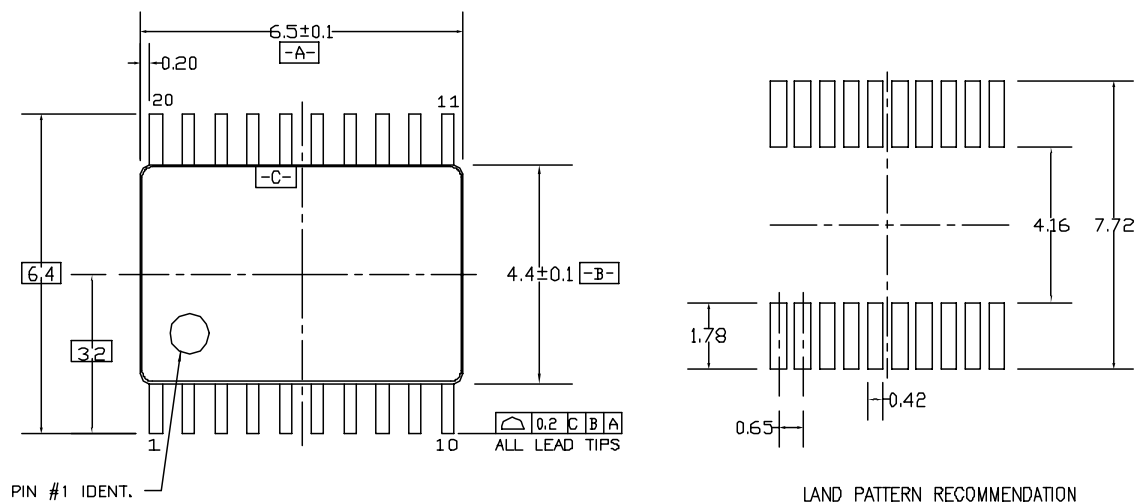


MSA20REVB

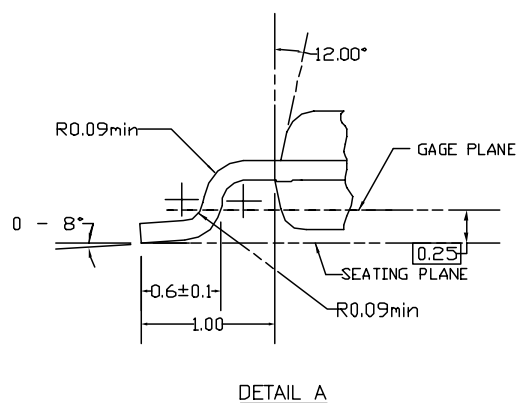
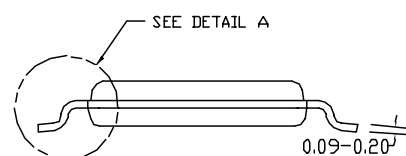
**Figure 10. 20-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide Package Number MSA20**

### Physical Dimensions (Continued)

Dimensions are in millimeters unless otherwise noted.



DIMENSIONS ARE IN MILLIMETERS



NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.


MTC20REV D1

**Figure 11. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide  
Package Number MTC20**



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FACT Quiet Series <sup>™</sup>	OPTOPLANAR <sup>®</sup>	SuperSOT <sup>™</sup> -6	
FACT <sup>®</sup>	PACMAN <sup>™</sup>	SuperSOT <sup>™</sup> -8	
FAST <sup>®</sup>	POP <sup>™</sup>	SyncFET <sup>™</sup>	
FASTr <sup>™</sup>	Power220 <sup>®</sup>	TCM <sup>™</sup>	
FPS <sup>™</sup>	Power247 <sup>®</sup>	The Power Franchise <sup>®</sup>	
FRFET <sup>®</sup>	PowerEdge <sup>™</sup>	 <sup>™</sup>	
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Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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